# INTEGRATED CIRCUITS

# DATA SHEET

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# 74LVC541A Octal buffer/line driver with 5-volt tolerant inputs/outputs (3-State)

Product specification Supercedes data of 1997 Oct 27 IC24 Data Handbook

1998 Jul 29

Philips Semiconductors





## 74LVC541A

#### FEATURES

- 5-volt tolerant inputs/outputs, for interfacing with 5-volt logic
- Wide supply voltage range of 2.7V to 3.6V
- Complies with JEDEC standard no. 8-1A
- CMOS low power consumption
- Direct interface with TTL levels
- 5 Volt tolerant inputs/outputs, for interfacing with 5 Volt logic

#### DESCRIPTION

The 74LVC541A is a high performance, low-power, low-voltage Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3V or 5.0V devices. In 3-State operation, outputs can handle 5V. This feature allows the use of these devices as translators in a mixed 3.3V/5V environment.

The 74LVC541A is an octal non-inverting buffer/line driver with 5-volt tolerant inputs/outputs. The 3-State outputs are controlled by the output enable inputs  $\overline{OE1}$  and  $\overline{OE2}$ .

#### QUICK REFERENCE DATA

GND = 0 V;  $T_{amb} = 25^{\circ}C$ ;  $t_r = t_f \le 2.5 \text{ ns}$ 

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay An to Yn	C <sub>L</sub> = 50 pF; V <sub>CC</sub> = 3.3 V	3.3	ns
CI	Input capacitance	OM.I.	5.0	pF
CPD	Power dissipation capacitance per buffer	Notes 1 and 2	20	pF

#### NOTES:

- f<sub>i</sub> = input frequency in MHz; C<sub>L</sub> = output load capacitance in pF;
- $f_o$  = output frequency in MHz;  $V_{CC}$  = supply voltage in V;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs.}$ 

2. The condition is  $V_I = GND$  to  $V_{CC}$ 

#### ORDERING INFORMATION

2. The condition is $V_I = GND$ to $V_{CC}$						
ORDERING INFORMATION						
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #		
20-Pin Plastic SO	-40°C to +85°C	74LVC541A D	74LVC541A D	SOT163-1		
20-Pin Plastic SSOP Type II	-40°C to +85°C	74LVC541A DB	74LVC541A DB	SOT339-1		
20-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVC541A PW	7LVC541APW DH	SOT360-1		

#### PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 19	OE1, OE2	Output enable inputs (active LOW)
2, 3, 4, 5, 6, 7, 8, 9	A0 to A7	Data inputs
10	GND	Ground (0 V)
18, 17, 16, 15, 14, 13, 12, 11	Y0 to Y7	Bus outputs
20	V <sub>CC</sub>	Positive supply voltage

#### **FUNCTION TABLE**

INPUTS	INPU	JTS 🚽	OUTPUT
OE1	OE2	An	Yn
1.760	CO <sub>FU</sub>	L	WW.L
W.4001	CGW.	н	HLUOS
×100	H	х	Z
H. 10	X	X	Z 100

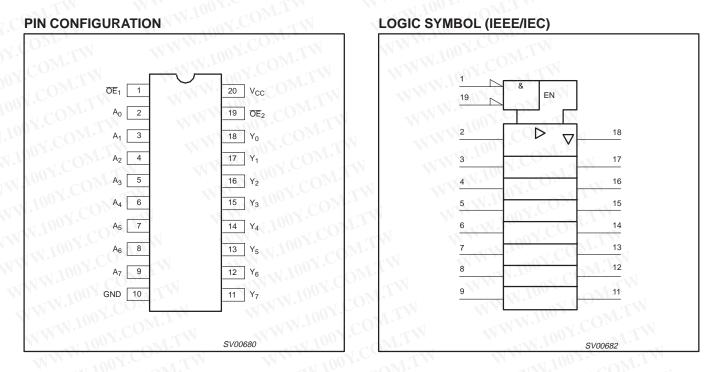
L = LOW voltage level

X = don't care

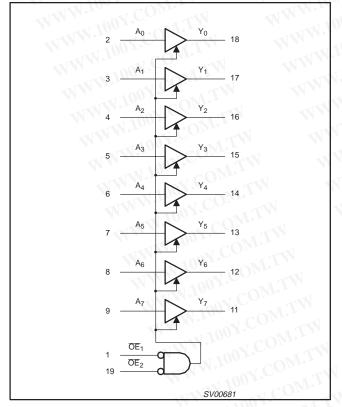
Z = high impedance OFF-state

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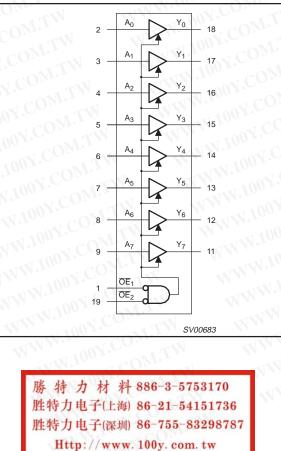
### 74LVC541A



#### LOGIC SYMBOL



#### **FUNCTIONAL DIAGRAM**



74LVC541A

#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	CONDITIONS	LIN		
STIVIDUL		CONDITIONS	MIN	MAX	
N C	DC supply voltage (for max. speed performance)	WW 100X.	2.7		v
Vcc	DC supply voltage (for low-voltage applications)	NWW MAN	1.2	3.6	ĺ
V	DC input voltage range	WW.100	0 0	5.5	V
V	DC output voltage range; output HIGH or LOW state	W 1001	0	V <sub>CC</sub>	v
Vo	DC output voltage range; output 3-State	NNN 100	0	5.5	1 <sup>×</sup>
Tamb	Operating free-air temperature range	N NWW.	-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	$V_{CC} = 1.2 \text{ to } 2.7 \text{V}$ $V_{CC} = 2.7 \text{ to } 3.6 \text{V}$		20 10	ns/V

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#### **ABSOLUTE MAXIMUM RATINGS<sup>1</sup>**

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT	
V <sub>CC</sub>	DC supply voltage	WW WW	-0.5 to +6.5	V	
IIK	DC input diode current	V <sub>1</sub> < 0	-50	mA	
VI	DC input voltage	Note 2	-0.5 to +5.5	V	
IOK	DC output diode current	$V_{O} > V_{CC}$ or $V_{O} < 0$	±50	mA	
Vo	DC output voltage; output HIGH or LOW	Note 2	–0.5 to V <sub>CC</sub> +0.5	v	
MM.	DC output voltage; output 3-State	Note 2	-0.5 to +6.5		
IO	DC output diode current	$V_{O} = 0$ to $V_{CC}$	±50	mA	
I <sub>GND</sub> , I <sub>CC</sub>	DC V <sub>CC</sub> or GND current	NW MILLOOY.CONTRA	±100	mA	
T <sub>stg</sub>	Storage temperature range	WWW. CON TW	-60 to +150	°C	
P <sub>TOT</sub>	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW	

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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	W	L					
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -	+85°C	דואט [		
COM	TW WWW.100Y.	WITH WWW 100Y.CC	MIN	TYP <sup>1</sup>	MAX	]	
	VIH HIGH level Input voltage	$V_{CC} = 1.2V$	Vcc				
V <sub>IH</sub> HIGH level Input voltage	nigh level input voltage	V <sub>CC</sub> = 2.7 to 3.6V	2.0				
N CO	LOW Invel Input veltage	$V_{CC} = 1.2V$	COMP	N	GND	v	
VIL	LOW level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V	COM.,		0.8	] `	
100%.	ON.TH WILL	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -12\text{mA}$	V <sub>CC</sub> -0.5				
- 100Y.		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -100 \mu A$	V <sub>CC</sub> -0.2	V <sub>CC</sub>			
VOH	HIGH level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = -18\text{mA}$	V <sub>CC</sub> -0.6	I.TV		1 `	
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = -24\text{mA}$	V <sub>CC</sub> -0.8	TIM	N	1	
NN.IOO	V.COM. WW	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 12mA$	. nov.C		0.40		
VOL	V <sub>OL</sub> LOW level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$	.Yool	OM.	0.20	V	
.W.I	JOL. COMIN I	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 24\text{mA}$	W.IO	COM	0.55	1	
h.	Input leakage current	$V_{CC} = 3.6V; V_{I} = 5.5V \text{ or GND}$	W.100 -	±0.1	±5	μA	
I <sub>OZ</sub>	3-State output OFF-state current	$V_{CC} = 3.6V; V_I = V_{IH} \text{ or } V_{IL}; V_O = 5.5V \text{ or GND}$	W.100	0.1	±5	μA	
IOFF	Power off leakage supply	$V_{CC} = 0.0V; V_1 \text{ or } V_0 = 5.5V$	W.10		±10	μA	
Icc	Quiescent supply current	$V_{CC} = 3.6V; V_{I} = V_{CC} \text{ or GND}; I_{O} = 0$		0.1	10	μA	
ΔI <sub>CC</sub>	Additional quiescent supply current per input pin	$V_{CC} = 2.7V$ to 3.6V; $V_{I} = V_{CC} - 0.6V$ ; $I_{O} = 0$	WWW.	5	500	μΑ	

#### **AC CHARACTERISTICS**

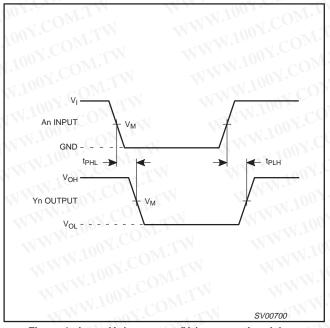
	PARAMETER	WAVEFORM	LIMITS						. NON.C	P
SYMBOL			V <sub>CC</sub> = 3.3V ±0.3V			V <sub>CC</sub> = 2.7V			V <sub>CC</sub> = 1.2V	UNIT
			MIN	TYP <sup>1</sup>	MAX	MIN	TYP	MAX	ТҮР	1.00
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay An to Yn	Figures 1, 3	1.5	3.3	5.6	1.5	3.9	6.6	14	ns
t <sub>PZH</sub> /t <sub>PZL</sub>	3-State output enable time OEn to Yn	Figures 2, 3	1.5	4.4	7.4	1.5	5.2	8.4	2.2	ns
t <sub>PHZ</sub> /t <sub>PLZ</sub>	3-State output disable time OEn to Yn	Figures 2, 3	1.5	3.8	6.0	1.5	4.3	7.0	11	ns

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#### AC WAVEFORMS

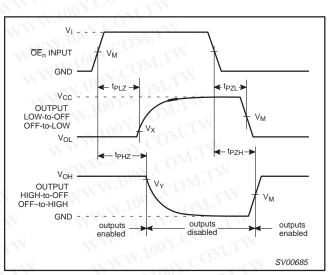
 $V_{M}$  = 1.5 V at  $V_{CC} \ge 2.7$  V  $V_{M} = 0.5 \cdot V_{CC}$  at  $V_{CC} < 2.7 V$  $V_X = V_{OL} + 0.3 \text{ V} \text{ at } V_{CC} \ge 2.7 \text{ V}$  $V_X = V_{OL} + 0.1 \cdot V_{CC}$  at  $V_{CC} < 2.7 V$  $V_{\rm Y} = V_{\rm OH} - 0.3$  V at  $V_{\rm CC} \ge 2.7$  V  $V_{Y} = V_{OH} - 0.1 \cdot V_{CC}$  at  $V_{CC} < 2.7$  V VOL and VOH are the typical output voltage drop that occur with the output load.

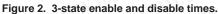




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#### TEST CIRCUIT

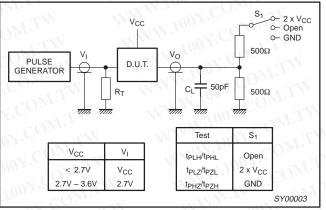
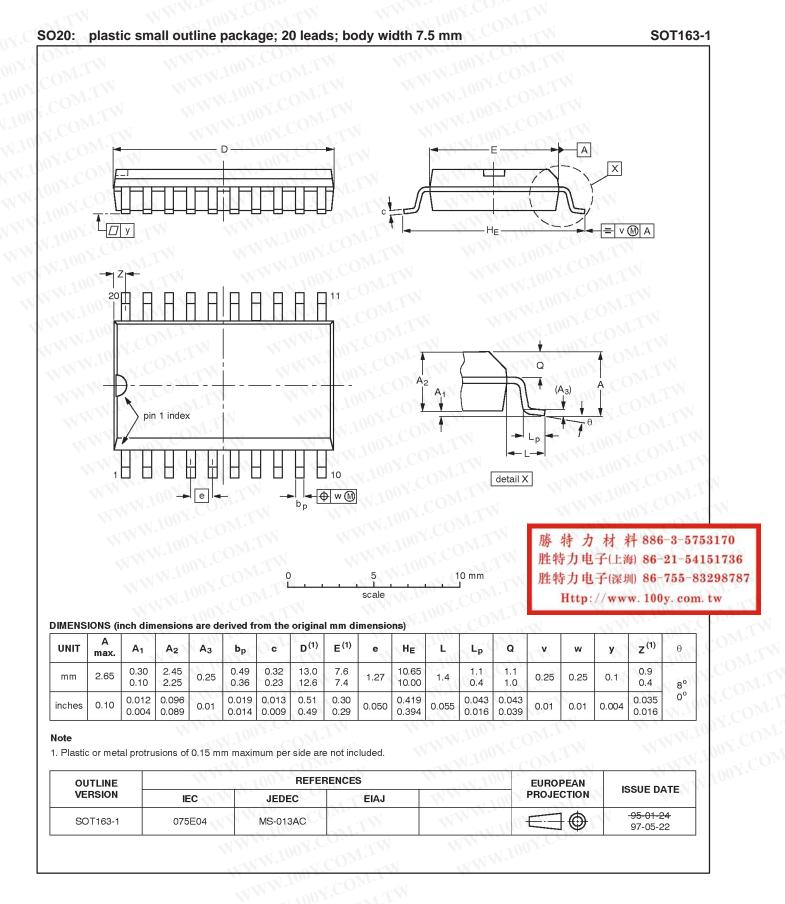


Figure 3. Load circuitry for switching times.

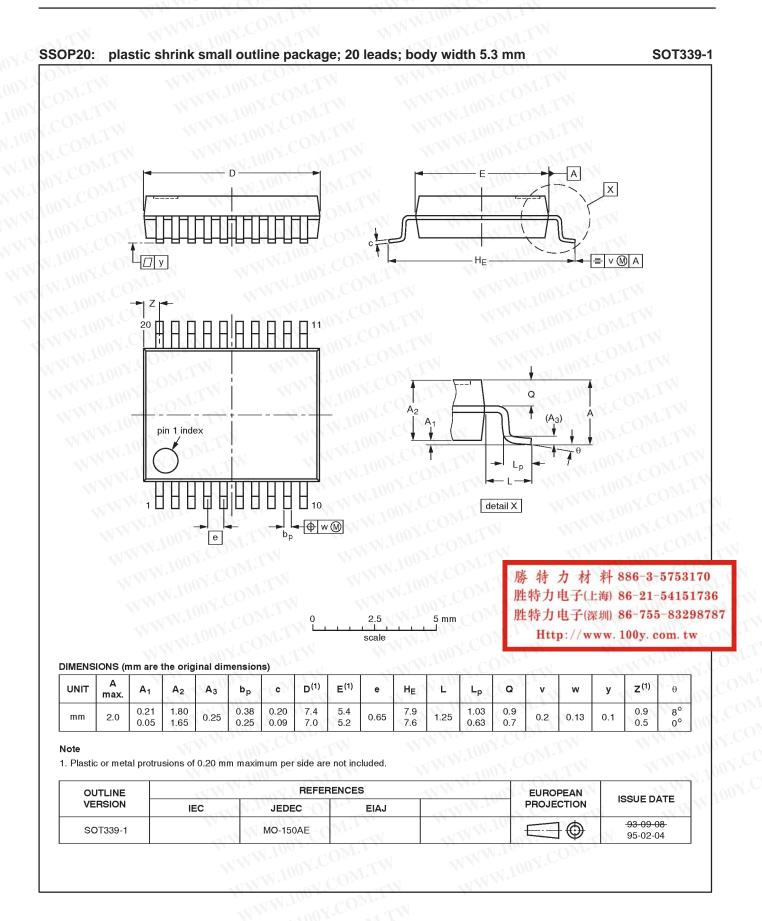
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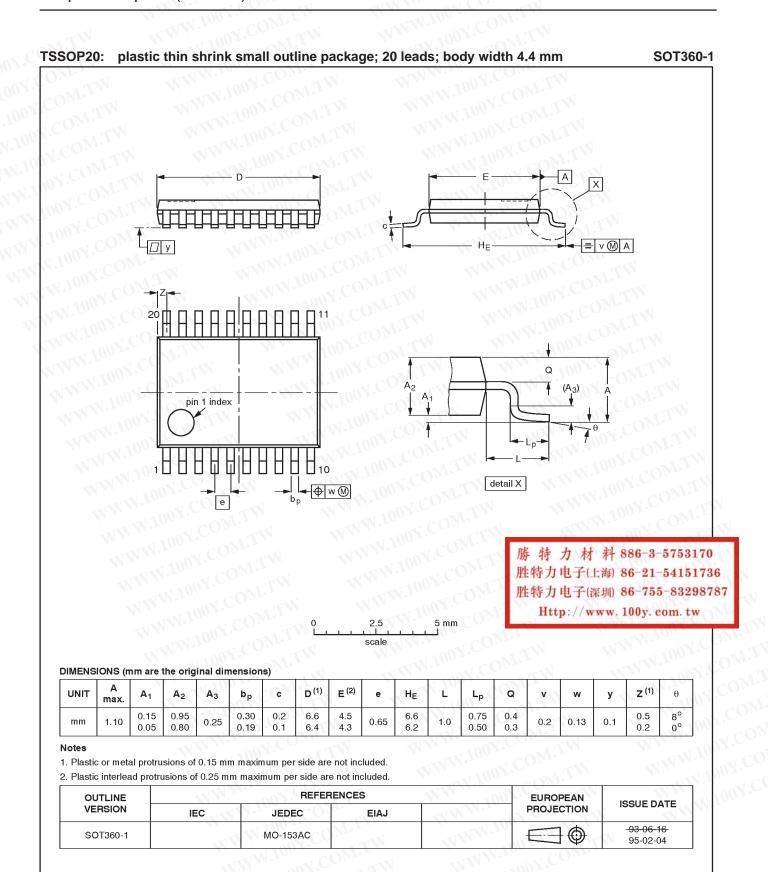


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Data sheet status	Product status	Definition <sup>[1]</sup>
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